











#### 5 V low drop voltage regulator with watchdog and reset

#### **Features**

- Output voltage tolerance ≤ ±2%
- 180 mA output current capability
- · Low-drop voltage
- · Very low standby current consumption
- Overtemperature protection
- · Reverse polarity protection
- · Short-circuit proof
- · Adjustable reset threshold
- · Watchdog for monitoring microprocessor
- · Power-on and undervoltage reset with programmable delay time
- Reset low down to  $V_0 = 1 \text{ V}$
- Wide temperature range
- Suitable for use in automotive electronics
- Green Product (RoHS-compliant)

#### **Potential applications**

- General automotive applications
- Supply for microcontroller

#### **Product validation**

Qualified for automotive applications.

Product validation according to AEC-Q100.

#### **Description**

The OPTIREG<sup> $^{\infty}$ </sup> linear TLE4263-2GM is a monolithic integrated very low dropout voltage regulator in an SMD package PG-DSO-14, especially designed for automotive applications. An input voltage up to 45 V is regulated to an output voltage of 5.0 V. The device is able to drive loads up to 180 mA. The IC is short-circuit proof by the implemented current limitation and has an integrated overtemperature shutdown. It additionally provides features like power-on and undervoltage reset with adjustable reset threshold, a watchdog circuit for monitoring a connected microcontroller and an inhibit input for enabling or disabling the device. The reset output RO is set to "low" in case the output voltage falls below the reset switching threshold  $V_{\rm Q,rt}$ . This threshold can be decreased down to 3.5 V by an external resistor divider. The power-on reset delay time can be programmed by the external delay capacitor  $C_{\rm D}$ . The watchdog circuit provides a monitoring function for microcontrollers: At missing pulses on the watchdog's input W the reset output RO is set to "low". The trigger time for the watchdog pulses can be set by the external capacitor  $C_{\rm D}$ . The IC can be switched off by the inhibit input, reducing the current consumption to typically 0 mA.

Туре	Package	Marking
TLE4263-2GM	PG-DSO-14	4263-2GM







## **Datasheet**





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1 Block diagram



# 1 Block diagram

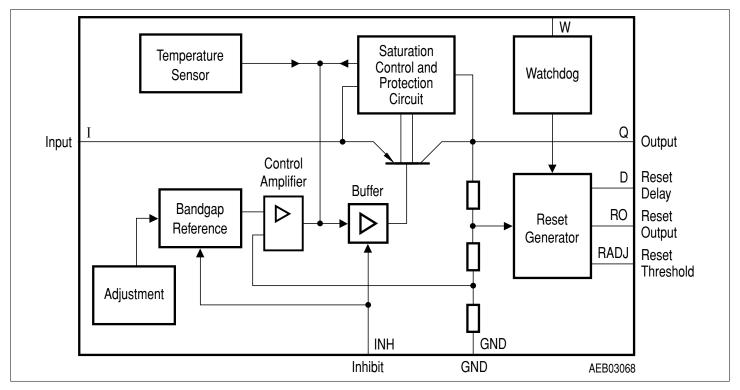


Figure 1 Block diagram

### **Datasheet**

2 Pin configuration



# 2 Pin configuration

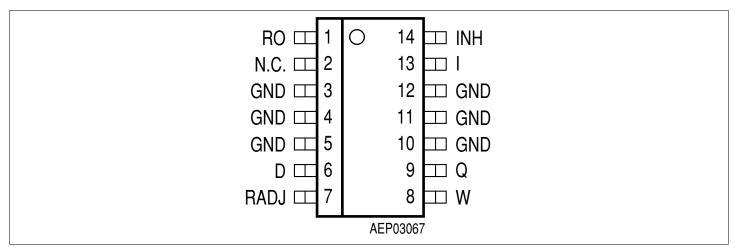


Figure 2 Pin configuration (top view)

Table 1 Pin definition and functions

Pin	Symbol	Function
1	RO	Reset output
		open-collector output connected to the output via an internal 30 $k\Omega$ pull-up resistor;
		leave open if the this function is not needed
2	N.C.	Not connected
3 - 5, 10 - 12	GND	Ground
6	D	Reset delay timing
		connect a ceramic capacitor to GND for adjusting the reset delay time/watchdog trigger time;
		leave open if this function is not needed
7	RADJ	Reset threshold adjust
		connect an external voltage divider to adjust the reset switching threshold;
		connect to GND for using internal threshold
8	W	Watchdog
		rising edge triggered input for monitoring a microcontroller;
		connect to GND if this function is not needed
9	Q	Output
		block to ground with a capacitor close to the IC terminals with a capacitance value $C_{\rm Q} \ge 22~\mu \rm F, ESR \le 3~\Omega$
13	I	Input
		for compensating line influences, a capacitor to GND close to the IC terminals is recommended
14	INH	Inhibit
		enables/disables the device;
		connect to I if the this function is not needed

#### **Datasheet**

3 General product characteristics



#### **General product characteristics** 3

#### **Absolute maximum ratings** 3.1

#### Absolute maximum ratings 1) Table 2

 $T_i$  = -40°C to +150°C; all voltages with respect to ground (unless otherwise specified)

Parameter	Symbol	Values			Unit	<b>Note or Test Condition</b>	Number
		Min.	Тур.	Max.			
Input I							
Input voltage	VI	-42	_	45	V	-	P_3.1.1
Input current	$I_1$	_	_	_	_	Internally limited	
Reset output RO							
Input voltage	$V_{RO}$	-0.3	_	42	V	-	P_3.1.2
Input current	$I_{RO}$	_	_	_	_	Internally limited	
Reset threshold RADJ		•					
Voltage	$V_{RADJ}$	-0.3	_	6	V	-	P_3.1.3
Reset delay D							<u> </u>
Voltage	$V_{D}$	-0.3	_	42	V	_	P_3.1.4
Current	$I_{D}$	_	_	_	_	Internally limited	
Output Q		•					
Voltage	$V_{\mathrm{Q}}$	0.30	_	7.0	V	-	P_3.1.5
Current	$I_{Q}$	_	_	-	_	Internally limited	
Inhibit INH							
Input voltage	$V_{INH}$	-42	_	45	V	_	P_3.1.6
Input current	I <sub>INH</sub>	_	_	_	_	Internally limited	
Watchdog W							
Voltage	$V_{W}$	-0.3	_	6	V	_	P_3.1.7
Ground GND		<u>'</u>			•		
Current	$I_{GND}$	-0.5	_	_	Α	_	P_3.1.8
Temperature		-1	-		1		
Junction temperature	T <sub>j</sub>	_	_	150	°C	-	P_3.1.9
Storage temperature	$T_{\rm stg}$	-50	_	150	°C	-	
ESD susceptibility							
Human body model (HBM)	V <sub>ESD_HBM</sub>	_	_	2	kV	2)	P_3.1.10
Charged device model (CBM)	V <sub>ESD_CDM</sub>	_	_	1	kV	3)	P_3.1.11

<sup>1)</sup> 2) Not subject to production test, specified by design.

ESD HBM test according JEDEC JESD22-A114.

<sup>3)</sup> ESD CDM test according AEC/ESDA ESD-STM5 3.1-1999.

#### **Datasheet**

3 General product characteristics



#### Notes:

- 1. Stresses above the ones listed here may cause permanent damage to the device. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.
- 2. Integrated protection functions are designed to prevent IC destruction under fault conditions described in the datasheet. Fault conditions are considered as "outside" normal operating range. Protection functions are not designed for continuous repetitive operation.

## 3.2 Functional range

Table 3 Functional range

Parameter	Symbol	Values		Unit	Note or Test Condition	Number	
		Min.	Тур.	Max.			
Input voltage	VI	5.5	_	45	٧	1)	P_3.2.1
Junction temperature	T <sub>j</sub>	-40	-	150	°C	-	P_3.2.2

<sup>1)</sup> Corresponds with characteristics of drop voltage, output current and power description (see Typical performance characteristics).

Note:

Within the functional range the IC operates as described in the circuit description. The electrical characteristics are specified within the conditions given in the related electrical characteristics table.

#### 3.3 Thermal resistance

Table 4 Thermal resistance

Parameter	Symbol	Values		Unit	Note or Test Condition	Number	
		Min.	Тур.	Max.			
Junction to case	$R_{thJC}$	_	26	_	K/W	1) Measured to exposed pad	P_3.3.1
Junction to ambient	$R_{thJA}$	_	53	_	K/W	2)	P_3.3.2
Junction to ambient	$R_{thJA}$	_	109	_	K/W	<sup>3)</sup> Footprint only	P_3.3.3
Junction to ambient	$R_{thJA}$	-	77	_	K/W	<sup>2)</sup> 300 mm <sup>2</sup> heatsink area	P_3.3.4
Junction to ambient	$R_{thJA}$	-	68	_	K/W	<sup>2)</sup> 600 mm <sup>2</sup> heatsink area	P_3.3.5

<sup>1)</sup> Not subject to production test, specified by design.

<sup>2)</sup> Specified R<sub>thJA</sub> value is according to JEDEC JESD51-2,-5,-7 at natural convection on FR4 2s2p board; The product (chip+package) was simulated on a 76.2 × 114.3 × 1.5 mm<sup>3</sup> board with 2 inner copper layers (2 × 70 μm Cu, 2 × 35 μm Cu). Where applicable a thermal via array under the exposed pad contacted the first inner copper layer.

<sup>3)</sup> Specified  $R_{\text{thJA}}$  value is according to JEDEC JESD 51-3 at natural convection on FR4 1s0p board; The product (chip+package) was simulated on a 76.2 × 114.3 × 1.5 mm<sup>3</sup> board with 1 copper layer (1 × 70  $\mu$ m Cu).

#### **Datasheet**

4 Functional description



#### **Functional description** 4

The control amplifier compares a reference voltage to a voltage that is proportional to the output voltage and drives the base of the series transistor via a buffer. Saturation control as a function of the load current prevents any oversaturation of the power element. The device also has a number of internal circuits for protection against:

- Overload
- Overtemperature
- Reverse polarity

In case the externally scaled down output voltage at the reset adjust input falls below 1.35 V, the external reset delay capacitor  $C_D$  is discharged by the reset generator. When the voltage of the capacitor reaches the lower threshold  $V_{DRL}$ , a reset signal occurs at the reset output and is held until the upper threshold  $V_{\rm DU}$  is exceeded. If the reset threshold input is connected to GND, reset is triggered at an output voltage of typically 4.65 V.

#### 4.1 **Choosing external components**

The input capacitor  $C_1$  is necessary for compensation of line influences. Using a resistor of approx. 1  $\Omega$  in series with  $C_1$ , the oscillating circuit consisting of input inductivity and input capacitance can be damped. The output capacitor is necessary for the stability of the regulating circuit. Stability is ensured at values  $C_0 \ge 22 \,\mu\text{F}$  and an ESR of  $\le 3 \,\Omega$  within the operating temperature range. For small tolerances of the reset delay the spread of the capacitance of the delay capacitor and its temperature coefficient should be noted.

#### 4.2 **Electrical characteristics**

#### Table 5 **Electrical characteristics**

 $V_{\rm I}$  = 13.5 V;  $V_{\rm INH}$  > 3.6 V  $T_{\rm i}$  = -40°C to +150°C; (unless specified otherwise)

Parameter	Symbol	Values			Unit	<b>Note or Test Condition</b>	Number
		Min.	Тур.	Max.			
Normal operation			•				
Output voltage	$V_{\mathrm{Q}}$	4.90	5.00	5.10	V	5 mA $\leq I_Q \leq$ 150 mA; 6 V $\leq V_I \leq$ 28 V	P_4.2.1
Output voltage	$V_{\mathrm{Q}}$	4.90	5.00	5.10	V	$6 \text{ V} \le V_1 \le 32 \text{ V};$ $I_Q = 100 \text{ mA};$ $T_j = 100^{\circ}\text{C}$	P_4.2.2
Output current limitation	I <sub>Q,max</sub>	180	250	400	mA	V <sub>Q</sub> = 4.8 V	P_4.2.3
Current consumption; $I_q = I_l - I_Q$	Iq	-	0	10	μΑ	$V_{\text{INH}} = 0 \text{ V};$ $T_{\text{j}} \le 115^{\circ}\text{C}$	P_4.2.4
Current consumption; $I_q = I_1 - I_Q$	Iq	-	0.90	1.30	mA	$I_Q = 0 \text{ mA}$	P_4.2.5
Current consumption; $I_q = I_1 - I_Q$	Iq	-	10	18	mA	I <sub>Q</sub> = 150 mA	P_4.2.6
Current consumption; $I_q = I_1 - I_Q$	Iq	-	15	24	mA	$I_{\rm Q}$ = 150 mA; $V_{\rm I}$ = 4.5 V	P_4.2.7
Dropout voltage	$V_{\rm dr}$	_	0.35	0.50	V	<sup>1)</sup> I <sub>Q</sub> = 150 mA	P_4.2.8

(table continues...)

#### **Datasheet**

4 Functional description



## Table 5 (continued) Electrical characteristics

 $V_{\rm I}$  = 13.5 V;  $V_{\rm INH}$  > 3.6 V  $T_{\rm j}$  = -40°C to +150°C; (unless specified otherwise)

Parameter	Symbol	Values			Unit	<b>Note or Test Condition</b>	Number
		Min.	Тур.	Max.			
Load regulation	$\Delta V_{\mathrm{Q,lo}}$	_	_	25	mV	$I_{\rm Q}$ = 5 mA to 150 mA	P_4.2.9
Line regulation	$\Delta V_{\mathrm{Q,li}}$	-	3	25	mV	$V_1 = 6 \text{ V to } 28 \text{ V};$ $I_Q = 150 \text{ mA}$	P_4.2.10
Power supply ripple rejection	PSRR	_	54	_	dB	$rac{2}{V_r} = 100 \text{ Hz};$ $rac{V_r}{V_r} = 0.5 \text{ Vpp}$	P_4.2.11
Reset generator							
Switching threshold	$V_{Q,rt}$	4.5	4.65	4.8	V	$V_{\text{RADJ}} = 0 \text{ V}$	P_4.2.12
Reset adjust threshold	$V_{RADJ,th}$	1.26	1.36	1.44	V	$3.5 \mathrm{V} \leq V_\mathrm{Q} < 5 \mathrm{V}$	P_4.2.13
Reset low voltage	$V_{\rm RO,l}$	-	0.10	0.40	V	I <sub>RO</sub> = 1 mA	P_4.2.14
Saturation voltage	$V_{D,sat}$	_	50	110	mV	$V_{\rm Q} < V_{\rm RAD,th}$	P_4.2.15
Upper timing threshold	$V_{DU}$	1.40	1.70	2.20	V	-	P_4.2.16
Lower reset timing threshold	$V_{DRL}$	0.20	0.35	0.59	V	_	P_4.2.17
Charge current	I <sub>D,ch</sub>	40	60	88	μΑ	-	P_4.2.18
Reset delay time	t <sub>rd</sub>	1.3	2.8	4.1	ms	C <sub>D</sub> = 100 nF	P_4.2.19
Reset reaction time	t <sub>rr</sub>	0.5	1.2	4.0	μs	C <sub>D</sub> = 100 nF	P_4.2.20
Watchdog							
Discharge current	I <sub>D,wd</sub>	4.40	6.25	11.0	μΑ	V <sub>D</sub> = 1.0 V	P_4.2.22
Upper timing threshold	$V_{DU}$	1.40	1.70	2.20	V	-	P_4.2.24
Lower timing threshold	$V_{DWL}$	0.20	0.35	0.59	V	_	P_4.2.25
Watchdog trigger time	$T_{\mathrm{WI,tr}}$	14.5	21.5	27	ms	$C_D = 100 \text{ nF};$ $V_Q > V_{Q,RT}$	P_4.2.26
Watchdog output low time	$T_{\mathrm{WD,L}}$	1.0	2.10	3.50	ms	$C_D = 100 \text{ nF};$ $V_Q > V_{Q,RT}$	P_4.2.27
Watchdog period	$T_{\mathrm{WI,p}}$	15.5	23.6	30.5	ms	$C_{\rm D} = 100  \rm nF;$	P_4.2.28
$T_{\text{WI,p}} = T_{\text{WD,L}} + T_{\text{WI,tr}}$						$V_{Q} > V_{Q,RT}$	
Inhibit							
Switching voltage	V <sub>INH,ON</sub>	3.6	_	_	V	IC turned on	P_4.2.29
Turn-OFF voltage	V <sub>INH,OFF</sub>	_	_	0.8	V	IC turned off	P_4.2.30
Input current	I <sub>INH</sub>	5	10	27	μA	V <sub>INH</sub> = 5 V	P_4.2.31

<sup>1)</sup> Drop voltage =  $V_1 - V_Q$  (measured when the output voltage has dropped 100 mV from the nominal value obtained at 6 V input).

**Note**: The reset output is "low" within the range  $V_Q = 1 V$  to  $V_{Q,rt}$ .

<sup>2)</sup> Not subject to production test, specified by design.

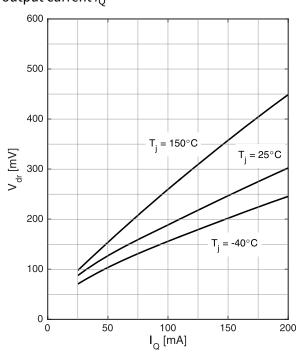
### **Datasheet**

4 Functional description

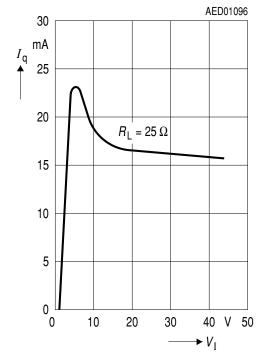


# 4.3 Typical performance characteristics

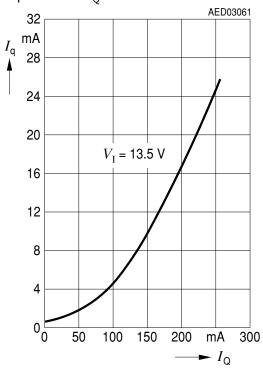
Drop voltage  $V_{\rm dr}$  versus output current  $I_{\rm Q}$ 



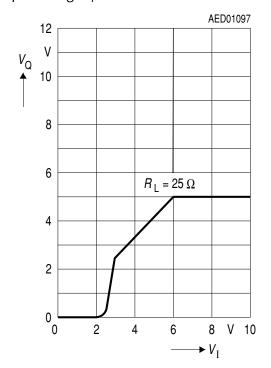
Current consumption  $I_q$  versus input voltage  $V_l$ 



Current consumption  $I_q$  versus output current  $I_Q$ 



Output voltage  $V_Q$  versus input voltage  $V_I$ 

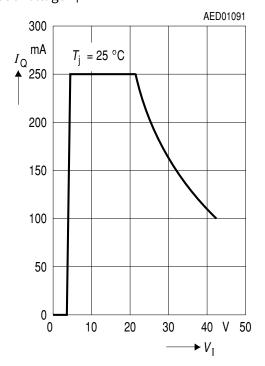


### **Datasheet**

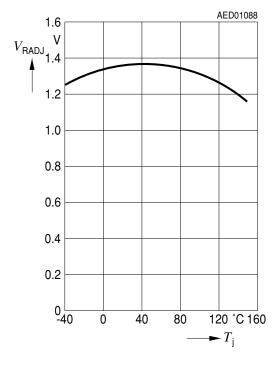
4 Functional description



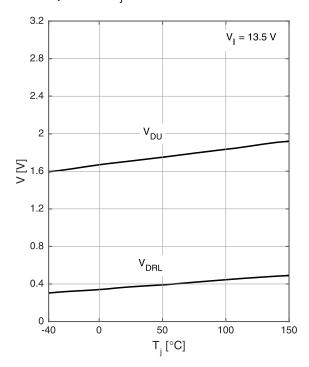
# Output current $I_Q$ versus input voltage $V_I$



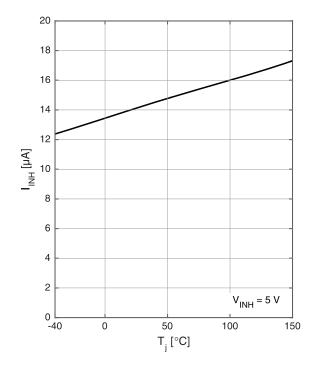
# Reset switching threshold $V_{\rm RADJ}$ versus junction temperature $T_{\rm j}$



# Timing threshold voltage $V_{\rm DU}$ and $V_{\rm DRL}$ versus junction temperature $T_{\rm i}$



# Current consumption of inhibit $I_{\text{INH}}$ versus junction temperature $T_{\text{j}}$

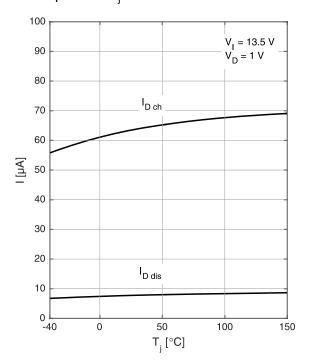


### **Datasheet**

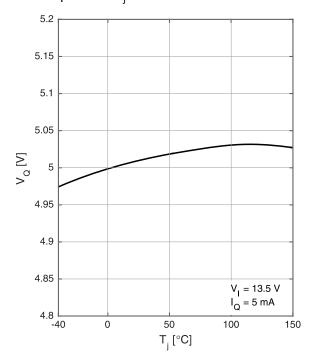
4 Functional description



Charge current and discharge current  $I_{\rm D,ch}$ ;  $I_{\rm D,dis}$  versus junction temperature  $T_{\rm j}$ 



Output voltage  $V_Q$  versus junction temperature  $T_i$ 

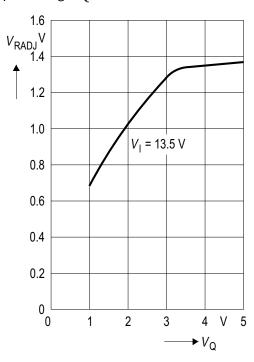


#### **Datasheet**

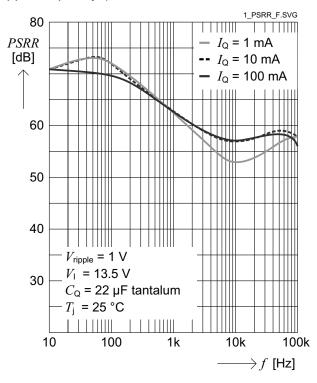
4 Functional description



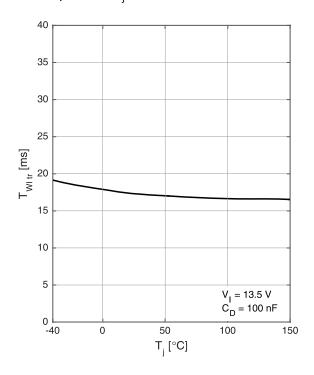
Undervoltage reset adjust threshold  $V_{\mathsf{RADJ}}$  versus output voltage  $V_{\mathsf{O}}$ 



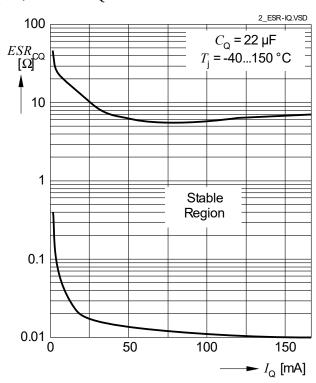
Power supply ripple rejection PSRR versus ripple frequency  $f_r$ 



Pulse time  $T_{WI,tr}$  versus junction temperature  $T_i$ 



Output capacitor series resistance ESR  $C_Q$  versus output current  $I_Q$ 



#### **Datasheet**

5 Application information



## 5 Application information

Note:

The following information is given as a hint for the implementation of the device only and shall not be regarded as a description or warranty of a certain functionality condition or quality of the device.

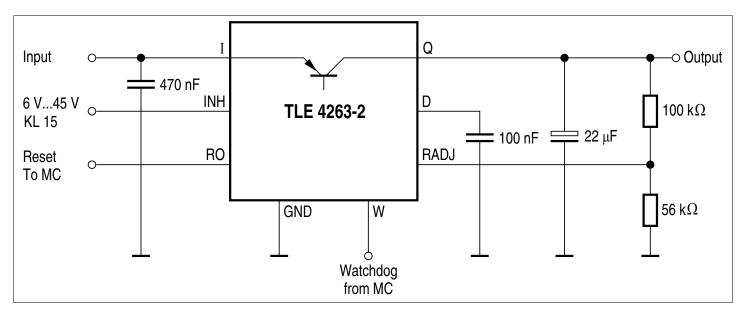


Figure 3 Application circuit

Note:

This is a very simplified example of an application circuit. The function must be verified in the real application.

5 Application information



### 5.1 Reset

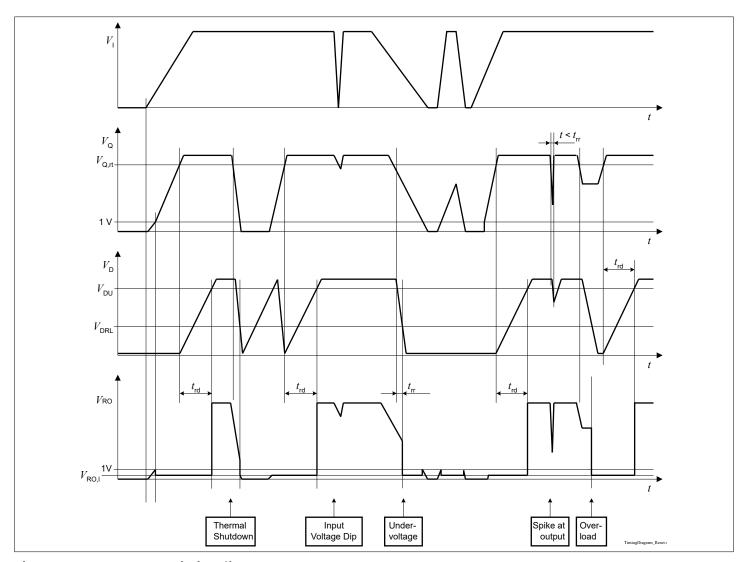


Figure 4 Reset timing diagram

## 5.2 Power-on reset delay time

If the application requires a power-on reset delay time  $t_{rd}$  different from the value given in Reset generator, the delay capacitor's value can be derived from these specified values and the desired power-on delay time:

14

$$C_D = \frac{t_{rd.new}}{t_{rd}} \times 100 \, nF \tag{1}$$

#### with:

- $C_D$ : capacitance of the delay capacitor to be chosen
- $t_{rd.new}$ : desired power-on reset delay time
- $t_{rd}$ : power-on reset delay time specified in this datasheet

For a precise calculation also take the delay capacitor's tolerance into consideration.

5 Application information



## 5.3 Reset adjust function

The undervoltage reset switching threshold can be adjusted according to the application requirements by connecting an external voltage divider ( $R_{ADJ,1}$ ,  $R_{ADJ,2}$ ) at pin RADJ. For selecting the default threshold connect pin RADJ to GND. When dimensioning the voltage divider, take into consideration that an additional current constantly flows through the resistors.

With a voltage divider connected, the reset switching threshold  $V_{RT,new}$  is calculated as follows:

$$V_{RT,new} = \frac{R_{ADJ,1} + R_{ADJ,2}}{R_{ADJ,2}} \times V_{RADJ,th}$$
 (2)

with

- $V_{RT,new}$ : the desired new reset switching threshold
- $R_{ADJ,1}$ ,  $R_{ADJ,2}$ : resistors of the external voltage divider
- V<sub>RADJ.th</sub>: reset adjust switching threshold given in Reset generator

## 5.4 Watchdog

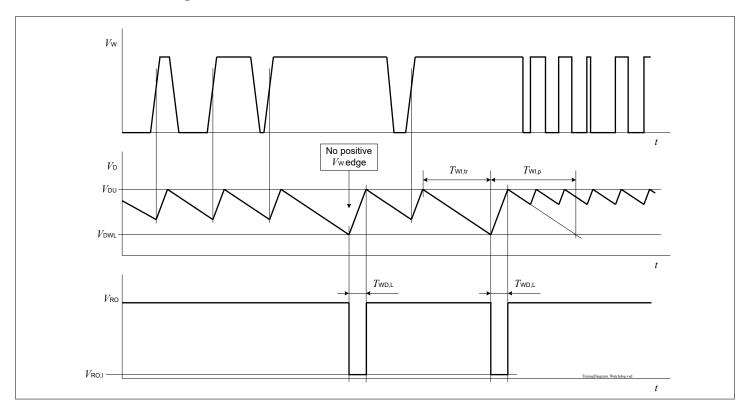


Figure 5 Timing of the watchdog function reset

#### **Datasheet**

5 Application information



### **Watchdog timing**

The period of the watchdog pulses must be smaller than the minimum watchdog trigger time which is set by the external reset delay capacitor  $C_D$ . Use the following formula for dimensioning  $C_D$ :

$$C_D = \frac{T_{WI,tr,new}}{T_{WI,tr}} \times 100 \, nF \tag{3}$$

with

- $C_D$ : capacitance of the delay capacitor to be chosen
- T<sub>WI,tr,new</sub>: desired watchdog trigger time
- T<sub>WI,tr</sub>: watchdog trigger time specified in Watchdog

6 Package information



## 6 Package information

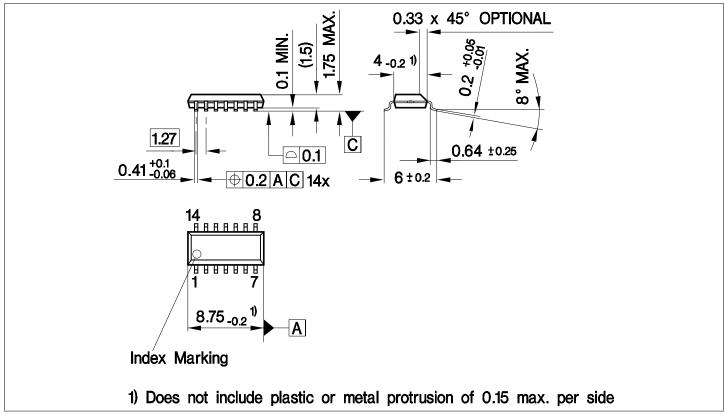


Figure 6 PG-DSO-14 (Plastic Dual Small Outline) 1)

#### **Green Product (RoHS-compliant)**

To meet the world-wide customer requirements for environmentally friendly products and to be compliant with government regulations the device is available as a green product. Green Products are RoHS-compliant (for example Pb-free finish on leads and suitable for Pb-free soldering according to IPC/JEDEC J-STD-020).

#### **Further information on packages**

https://www.infineon.com/packages

Dimension in mm

## **Datasheet**

7 Revision history



# 7 Revision history

Revision	Date	Changes
1.00	2024-10-11	Initial datasheet release

#### Trademarks

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Edition 2024-10-11 Published by Infineon Technologies AG 81726 Munich, Germany

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Document reference IFX-ace1727162148337 Z8F80451103

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